

Hyperfast power diode Rev. 1 — 6 July 2011

Product data sheet

Product profile 1.

1.1 General description

Hyperfast power diode in a SOD113 (2-lead TO-220F) plastic package.

1.2 Features and benefits

- Isolated plastic package
- Low reverse recovery current
- Low thermal resistance
- Reduces switching losses in associated MOSFET

1.3 Applications

Continuous Current Mode (CCM) Power Factor Correction (PFC)

- Half-bridge/full-bridge switched-mode power supplies
- Half-bridge lighting ballasts

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	-	500	V
I _{F(AV)}	average forward current	square-wave pulse; $\bar{\delta}$ = 0.5; T_h = 103 °C; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	-	5	Α
Static cha	aracteristics					
V _F	forward voltage	$I_F = 5 \text{ A}$; $T_j = 25 \text{ °C}$; see Figure 5	-	1.5	2	V
		$I_F = 5 \text{ A}; T_j = 150 \text{ °C}; \text{ see } \frac{\text{Figure 5}}{}$	-	1.15	1.45	V
Dynamic	characteristics					
t _{rr}	reverse recovery time	$I_F = 5 \text{ A}; V_R = 400 \text{ V};$ $dI_F/dt = 500 \text{ A}/\mu\text{s}; T_j = 25 \text{ °C};$ $see \frac{Figure 6}{}$	-	16	-	ns



Pinning information

Table 2. **Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		v. 14. A
2	Α	anode	mb	K — A 001aaa020
mb	n.c.	mounting base; isolated	SOD113 (TO-220F)	

Ordering information 3.

Table 3. **Ordering information**

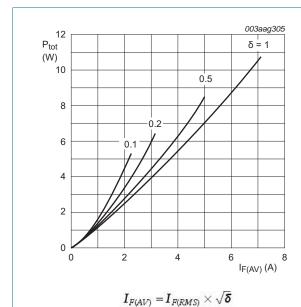
Type number	Package		
	Name	Description	Version
BYC5DX-500	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 2-lead TO-220 "full pack"	SOD113

4. Limiting values

Table 4. Limiting values

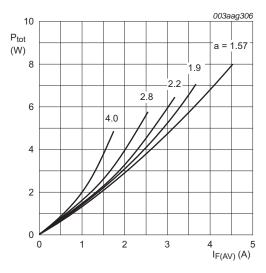
In accordance with the Absolute Maximum Rating System (IEC 60134).

		. ,			
Symbol	Parameter	Conditions	Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	500	V
V_{RWM}	crest working reverse voltage		-	500	V
V_R	reverse voltage	DC	-	500	V
I _{F(AV)}	average forward current	square-wave pulse; $\delta = 0.5$; $T_h = 103 ^{\circ}\text{C}$; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	5	A
I _{FRM}	repetitive peak forward current	square-wave pulse; $\delta = 0.5$; $t_p = 25 \mu s$; $T_h = 103 °C$	-	10	Α
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; sine-wave pulse; $T_{j(init)}$ = 25 °C; see <u>Figure 3</u>	-	40	Α
		t_p = 8.3 ms; sine-wave pulse; $T_{j(init)}$ = 25 °C; see <u>Figure 3</u>	-	44	Α
T _{stg}	storage temperature		-40	150	°C
T _i	junction temperature		-	150	°C



 $V_0 = 1.141 \text{ V}; R_s = 0.057 \Omega$

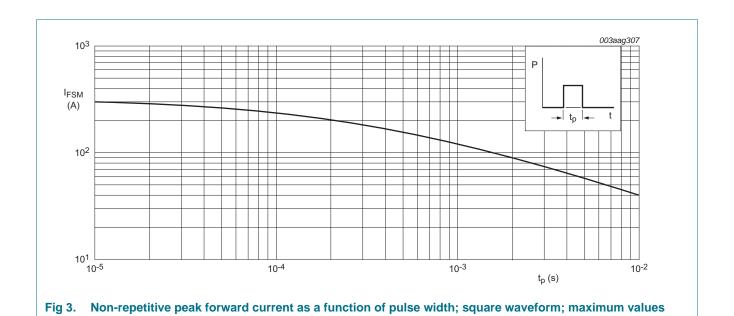
Fig 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



a = form factor =
$$I_{F(RMS)}/I_{F(AV)}$$

 $V_o = 1.141 \, \text{V}; \, R_s = 0.057 \, \Omega$

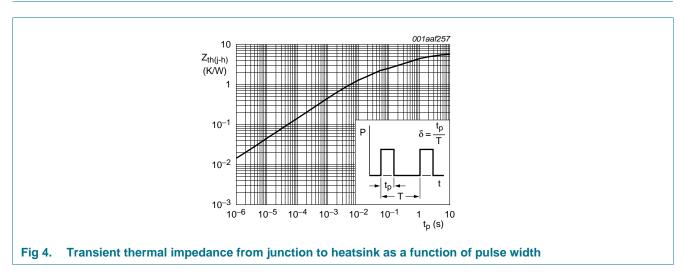
Fig 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values



5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-h)}$	thermal resistance from	without heatsink compound	-	-	7.2	K/W
	junction to heatsink	with heatsink compound; see Figure 4	-	-	5.5	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air		-	60	-	K/W



6. Isolation characteristics

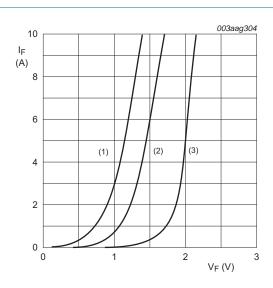
Table 6. Isolation characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{isol(RMS)}$	RMS isolation voltage	50 Hz ≤ f ≤ 60 Hz; RH ≤ 65 %; from all pins to external heatsink; sinusoidal waveform; clean and dust free	-	-	2500	V
C _{isol}	isolation capacitance	f = 1 MHz; from cathode to external heatsink	-	10	-	pF

7. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara				. , ,	1110121	• • • • • • • • • • • • • • • • • • • •
		L 5 A T 05 00 5		4.5		
V_{F}	forward voltage	$I_F = 5 \text{ A}$; $T_j = 25 \text{ °C}$; see <u>Figure 5</u>	-	1.5	2	V
		$I_F = 5 \text{ A}$; $T_j = 150 \text{ °C}$; see Figure 5	-	1.15	1.45	V
		$I_F = 10 \text{ A}; T_j = 150 ^{\circ}\text{C}; \text{ see } \frac{\text{Figure 5}}{}$	-	1.4	1.7	V
I _R reverse cur	reverse current	$V_R = 500 \text{ V}; T_j = 100 ^{\circ}\text{C}$	-	0.9	3	mΑ
		V _R = 500 V	-	9	40	μΑ
Dynamic ch	naracteristics					
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 50 \text{ A}/\mu\text{s}$; $T_j = 25 \text{ °C}$; see Figure 6	-	15	30	ns
		$I_F = 5 \text{ A}$; $V_R = 400 \text{ V}$; $dI_F/dt = 500 \text{ A/}\mu\text{s}$; $T_j = 25 \text{ °C}$; see Figure 6	-	16	-	ns
I _{RM}	peak reverse recovery current	$I_F = 5 \text{ A}$; $V_R = 400 \text{ V}$; $dI_F/dt = 500 \text{ A/}\mu\text{s}$; $T_j = 100 \text{ °C}$; see Figure 6	-	9.5	11	Α
		$I_F = 5 \text{ A}$; $V_R = 400 \text{ V}$; $dI_F/dt = 50 \text{ A}/\mu\text{s}$; $T_j = 125 \text{ °C}$; see Figure 6	-	0.9	3	Α
V_{FR}	forward recovery voltage	$I_F = 5 \text{ A}$; $dI_F/dt = 100 \text{ A/}\mu\text{s}$; $T_j = 25 \text{ °C}$; see Figure 7	-	9	11	V



- (1) $T_j = 150$ °C; typical values;
- (2) $T_j = 150$ °C; maxium values;
- (3) $T_j = 25$ °C; maxium values;

 $V_{\text{o}} = 1.141\,V;\,R_{\text{s}} = 0.057\,\Omega$

Fig 5. Forward current as a function of forward voltage

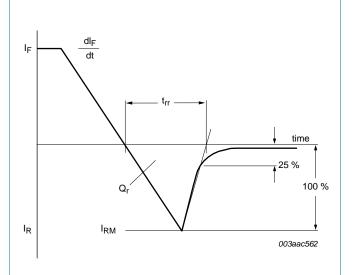


Fig 6. Reverse recovery definitions; ramp recovery

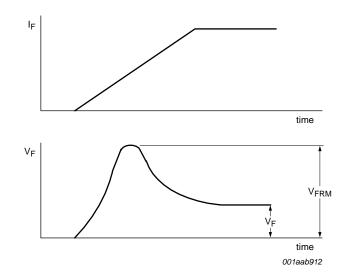


Fig 7. Forward recovery definitions

8. Package outline

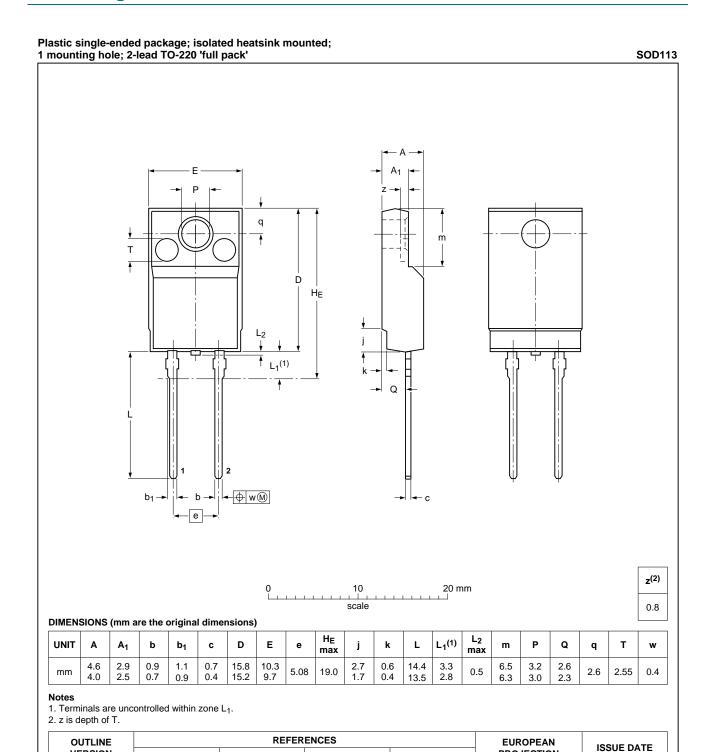


Fig 8. Package outline SOD113 (TO-220F)

IEC

02-04-09

07-06-18

PROJECTION

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JEITA

JEDEC

2-lead TO-220F

VERSION

SOD113



9. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BYC5DX-500 v.1	20110706	Product data sheet	-	-

10. Legal information

10.1 Data sheet status

Document status [1] [2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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